

Trench[™] Power MOSFET

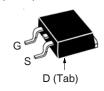
IXTA60N20T IXTP60N20T IXTQ60N20T

N-Channel Enhancement Mode For PDP Drivers Avalanche Rated

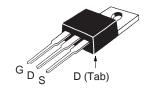


 $V_{DSS} = 200V$ $I_{D25} = 60A$ $R_{DS(on)} \le 40m\Omega$

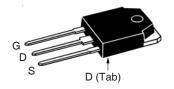
TO-263 AA (IXTA)



TO-220AB (IXTP)



TO-3P (IXTQ)



| G | = Gate | D | = Drain |
|---|----------|-----|---------|
| S | = Source | Tab | = Drain |

Features

- High Current Handling Capability
- 175°C Operating Temperature
- Avalanche Rated
- Fast Intrinsic Rectifier
- Low R_{DS(on)}

Advantages

- Easy to Mount
- Space Savings
- High Power Density

Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- DC Choppers
- AC Motor Drives
- Uninterruptible Power Supplies
- High Speed Power Switching Applications

| Symbol | Test Conditions | Maximum Ratings | | | |
|-------------------------------------|---|-------------------|-----------|--|--|
| V _{DSS} | T _J = 25°C to 175°C | 200 | V | | |
| \mathbf{V}_{DGR} | $T_{_{ m J}}$ = 25°C to 175°C, $R_{_{ m GS}}$ = 1M Ω | 200 | V | | |
| V _{GSS} | Continuous | ±20 | V | | |
| V _{GSM} | Transient | ±30 | V | | |
| I _{D25} | T _C = 25°C | 60 | А | | |
| I _{DM} | $\rm T_{\rm C}$ = 25°C, Pulse Width Limited by $\rm T_{\rm JM}$ | 150 | Α | | |
| IA | T _C = 25°C | 30 | А | | |
| E _{AS} | $T_{c} = 25^{\circ}C$ | 700 | mJ | | |
| P _D | T _C = 25°C | 500 | W | | |
| T | | -55 +175 | °C | | |
| T_{JM} | | 175 | °C | | |
| T _{stg} | | -55 +175 | °C | | |
| T _L T _{sold} | 1.6mm (0.062in.) from Case for 10s Plastic Body for 10 Seconds | 300 260 | °C | | |
| M _d | Mounting Torque (TO-220 &TO-3P) | 1.13 / 10 | Nm/lb.in. | | |
| Weight | TO-263 TO-220 TO-3P | 2.5 3.0 5.5 | g g | | |

| | | teristic Values Typ. Max. | | | |
|---------------------|---|--------------------------------|----|------|-----------|
| BV _{DSS} | $V_{gs} = 0V$, $I_D = 250\mu A$ | 200 | | | V |
| V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250\mu A$ | 3.0 | | 5.0 | V |
| GSS | $V_{GS} = \pm 20V, V_{DS} = 0V$ | | | ±200 | nA |
| I _{DSS} | $V_{DS} = V_{DSS}, V_{GS} = 0V$ | | | 1 | μΑ |
| | $T_J = 150^{\circ}C$ | | | 250 | μΑ |
| R _{DS(on)} | V _{GS} = 10V, I _D = 0.5 • I _{D25} , Note 1 | | 32 | 40 | $m\Omega$ |



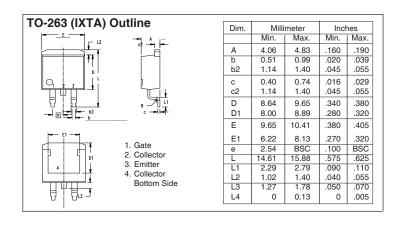


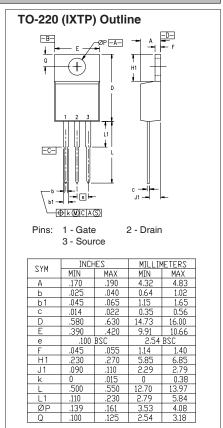
| | | Chara Min. | acteristic Values Typ. Max. | | |
|------------------------|---|---|------------------------------------|--------------|-----------|
| g _{fs} | | $V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$ | 40 | 62 | S |
| C _{iss} |) | | | 4530 | pF |
| C _{oss} | } | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$ | | 490 | pF |
| C _{rss} | J | | | 72 | pF |
| t _{d(on)} |) | Resistive Switching Times | | 22 | ns |
| t _r | | $V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ | | 13 | ns |
| t _{d(off)} | | $R_{G} = 10\Omega$ (External) | | 33 | ns |
| t _f | J | · · · · · · · · · · · · · · · · · · · | | 22 | ns |
| Q _{g(on)} |) | | | 73 | nC |
| \mathbf{Q}_{gs} | } | $V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ | | 22 | nC |
| Q _{gd} | J | | | 22 | nC |
| R _{thJC} | | | | | 0.30 °C/W |
| R _{thCS} | | TO-220 TO-3P | | 0.50 0.25 | °C/W |

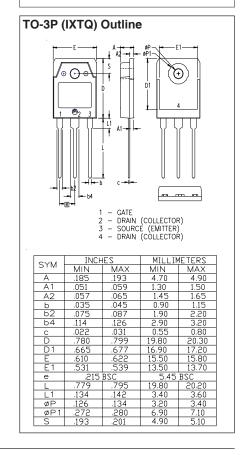
Source-Drain Diode

| Symbol Test Conditions Characteristic | | | Values | | |
|---------------------------------------|--|------|---------------|------|----|
| $(T_J = 25^{\circ}C,$ | Unless Otherwise Specified) | Min. | Тур. | Max. | |
| Is | $V_{GS} = 0V$ | | | 60 | Α |
| I _{SM} | Repetitive, Pulse Width Limited by $\mathrm{T}_{_{\mathrm{JM}}}$ | | | 240 | Α |
| V _{SD} | $I_{\rm F} = 60 {\rm A}, \ V_{\rm GS} = 0 {\rm V}, \ \ {\rm Note} \ 1$ | | | 1.3 | V |
| t _{rr} | I _F = 0.5 • I _{D25} , V _{GS} = 0V | | 118 | | ns |
| I _{RM} | $-di/dt = 100A/\mu s$ | | 9.3 | | Α |
| $Q_{_{RM}}$ | $V_R = 85V$ | | 550 | | nC |

Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.







IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



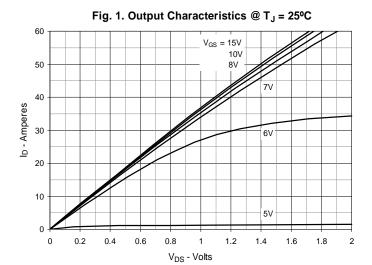
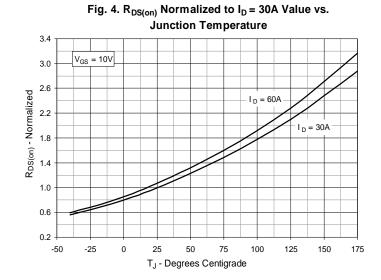
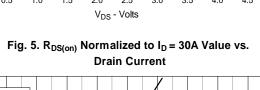
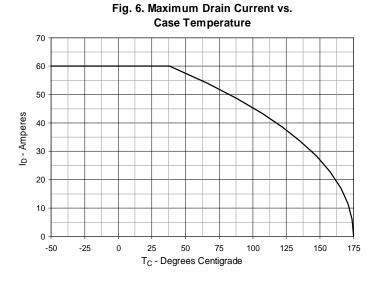


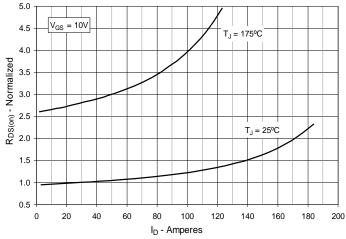
Fig. 2. Extended Output Characteristics @ T_J = 25°C 200 180 160 8V 140 ID - Amperes 120 100 80 60 6V 40 20 5V 0 0 2 6 12 14 8 10 16 18 20 V_{DS} - Volts

Fig. 3. Output Characteristics @ T_J = 150°C 60 = 15V 50 40 Ip - Amperes 30 20 5V 10 0 0.0 0.5 1.0 1.5 2.0 2.5

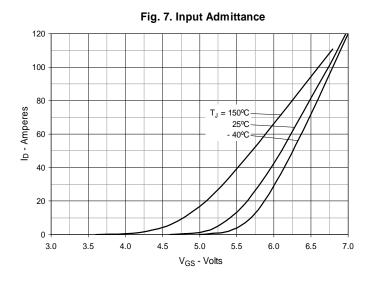


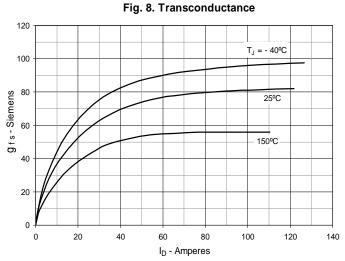


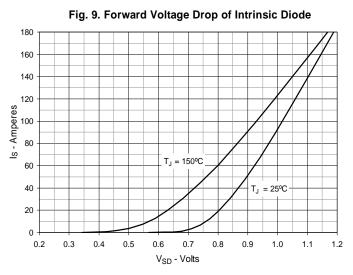


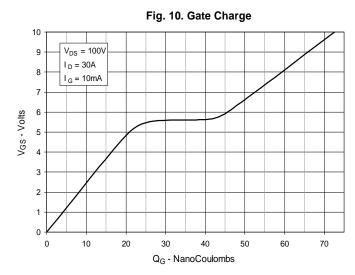


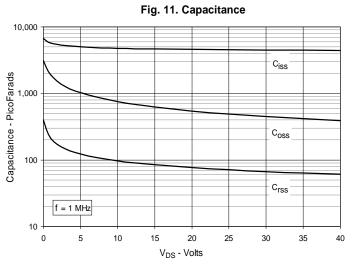


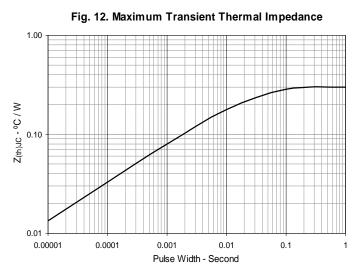












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